

www.ti.com

#### SNOS414I-AUGUST 1999-REVISED AUGUST 2013

# LMV721-N/LMV722 10MHz, Low Noise, Low Voltage, and Low Power Operational Amplifier

Check for Samples: LMV721-N, LMV722-N

## **FEATURES**

- (For Typical, 5 V Supply Values; Unless Otherwise Noted)
- Ensured 2.2V and 5.0V Performance
- Low Supply Current LMV721-N/2 930µA/Amplifier at 2.2V
- High Unity-Gain Bandwidth 10MHz
- Rail-to-Rail Output Swing
  - at 600Ω Load 120mV from Either Rail at 2.2V
  - at  $2k\Omega$  Load 50mV from Either Rail at 2.2V
- Input Common Mode Voltage Range Includes Ground
- Silicon Dust, SC70-5 Package 2.0x2.0x1.0 mm
- Input Voltage Noise 9 nV/\(\sqrt{Hz}\) at f = 1KHz

# **APPLICATIONS**

- Cellular an Cordless Phones
- Active Filter and Buffers
- Laptops and PDAs
- Battery Powered Electronics

### **Typical Application**

## DESCRIPTION

The LMV721-N (Single) and LMV722 (Dual) are low noise, low voltage, and low power op amps, that can be designed into a wide range of applications. The LMV721-N/LMV722 has a unity gain bandwidth of 10MHz, a slew rate of 5V/us, and a quiescent current of 930uA/amplifier at 2.2V.

The LMV721-N/722 are designed to provide optimal performance in low voltage and low noise systems. They provide rail-to-rail output swing into heavy loads. The input common-mode voltage range includes ground, and the maximum input offset voltage are 3.5mV (Over Temp) for the LMV721-N/LMV722. Their capacitive load capability is also good at low supply voltages. The operating range is from 2.2V to 5.5V.

The chip is built with TI's advanced Submicron Silicon-Gate BiCMOS process. The single version, LMV721-N, is available in 5 pin SOT-23 and a SC70 (new) package. The dual version, LMV722, is available in an SOIC-8 and VSSOP-8 package.

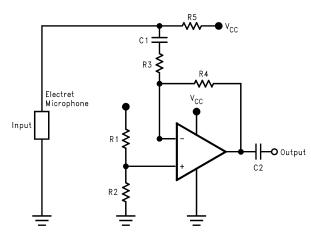


Figure 1. A Battery Powered Microphone Preamplifier

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. All trademarks are the property of their respective owners.

TEXAS INSTRUMENTS

www.ti.com

#### Absolute Maximum Ratings (1)(2)

ESD Tolerance <sup>(3)</sup>	
Human Body Model	2000V
Machine Model	100V
Differential Input Voltage	± Supply Voltage
Supply Voltage (V <sup>+</sup> – V <sup>-</sup> )	6V
Soldering Information	
Infrared or Convection (20 sec.)	235°C
Storage Temp. Range	−65°C to 150°C
Junction Temperature <sup>(4)</sup>	150°C

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured. For ensured specifications and the test conditions, see the Electrical Characteristics.

(2) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/ Distributors for availability and specifications.

(3) Human body model, 1.5 k $\Omega$  in series with 100 pF. Machine model, 200 $\Omega$  in series with 100 pF.

(4) The maximum power dissipation is a function of  $T_{J(max)}$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any ambient temperature is  $P_D = (T_{J(max)} - T_A)/\theta_{JA}$ . All numbers apply for packages soldered directly into a PC board.

## Operating Ratings <sup>(1)</sup>

Supply Voltage	2.2V to 5.5V
Temperature Range	-40°C ≤T <sub>J</sub> ≤85°C
Thermal Resistance ( $\theta_{JA}$ )	
Silicon Dust SC70-5 Pkg	440°C/W
Tiny SOT-23 package	265 °C/W
SOIC package, 8-pin Surface Mount	190°C/W
VSSOP package, 8-Pin Mini Surface Mount	235 °C/W
SOIC package, 14-Pin Surface Mount	145°C/W

(1) Applies to both single-supply and split-supply operation. Continuous short circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C. Output currents in excess of 30 mA over long term may adversely affect reliability.

## 2.2V DC Electrical Characteristics

Unless otherwise specified, all limits specified for  $T_J = 25^{\circ}C$ .  $V^+ = 2.2V$ ,  $V^- = 0V$ ,  $V_{CM} = V^+/2$ ,  $V_O = V^+/2$  and  $R_{\perp} > 1 \text{ M}\Omega$ . Boldface limits apply at the temperature extremes.

	Parameter	Test Conditions	Тур <sup>(1)</sup>	Limit <sup>(2)</sup>	Units
V <sub>OS</sub>	Input Offset Voltage		0.02	3 <b>3.5</b>	mV max
TCV <sub>OS</sub>	Input Offset Voltage Average Drift		0.6		µV/°C
I <sub>B</sub>	Input Bias Current		260		nA
I <sub>OS</sub>	Input Offset Current		25		nA
CMRR	Common Mode Rejection Ratio	$0V \le V_{CM} \le 1.3V$	88	70 <b>64</b>	dB min
PSRR	Power Supply Rejection Ratio	$2.2V \le V^+ \le 5V, V_0 = 0 V_{CM} = 0$	90	70 <b>64</b>	dB min
V <sub>CM</sub>	Input Common-Mode Voltage Range	For CMRR ≥ 50dB	-0.30		V
			1.3		V
A <sub>V</sub>	Large Signal Voltage Gain	$R_L$ =600Ω $V_O$ = 0.75V to 2.00V	81	75 <b>60</b>	dB min
		$\begin{array}{l} R_L = 2k\Omega \\ V_O = 0.50 V \text{ to } 2.10 V \end{array}$	84	75 <b>60</b>	dB min

(1) Typical Values represent the most likely parametric norm.

(2) All limits are specified by testing or statistical analysis.



#### www.ti.com

### 2.2V DC Electrical Characteristics (continued)

Unless otherwise specified, all limits specified for  $T_J = 25^{\circ}C$ . V<sup>+</sup> = 2.2V, V<sup>-</sup> = 0V, V<sub>CM</sub> = V<sup>+</sup>/2, V<sub>O</sub> = V<sup>+</sup>/2 and R<sub>L</sub> > 1 M $\Omega$ . **Boldface** limits apply at the temperature extremes.

Parameter		Test Conditions	Тур <sup>(1)</sup>	Limit <sup>(2)</sup>	Units
Vo	Output Swing	$R_L = 600\Omega$ to V <sup>+</sup> /2	2.125	2.090 <b>2.065</b>	V min
			0.071	0.120 <b>0.145</b>	V max
		$R_L = 2k\Omega$ to V <sup>+</sup> /2	2.177	2.150 <b>2.125</b>	V min
			0.056	0.080 <b>0.105</b>	V max
l <sub>O</sub>	I <sub>O</sub> Output Current	Sourcing, $V_0 = 0V$ $V_{IN}(diff) = \pm 0.5V$	14.9	10.0 <b>5.0</b>	mA min
		Sinking, $V_O = 2.2V$ $V_{IN}(diff) = \pm 0.5V$	17.6	10.0 <b>5.0</b>	mA min
I <sub>S</sub>	I <sub>S</sub> Supply Current	LMV721-N	0.93	1.2 <b>1.5</b>	mA
		LMV722	1.81	2.2 <b>2.6</b>	max

### 2.2V AC Electrical Characteristics

Unless otherwise specified, all limits specified for  $T_J = 25^{\circ}$ C. V<sup>+</sup> = 2.2V, V<sup>-</sup> = 0V, V<sub>CM</sub> = V<sup>+</sup>/2, V<sub>O</sub> = V<sup>+</sup>/2 and R<sub>L</sub> > 1 M $\Omega$ .**Boldface** limits apply at the temperature extremes.

Parameter		Test Conditions	Тур <sup>(1)</sup>	Units	
SR	Slew Rate	(2)	4.9	V/µs	
GBW	Gain-Bandwidth Product		10	MHz	
Φ <sub>m</sub>	Phase Margin		67.4	Deg	
G <sub>m</sub>	Gain Margin		-9.8	dB	
e <sub>n</sub>	Input-Referred Voltage Noise	f = 1 kHz	9	nV/√Hz	
i <sub>n</sub>	Input-Referred Current Noise	f = 1 kHz	0.3	pA/√Hz	
THD	Total Harmonic Distortion	$      f = 1 \text{ kHz } A_V = 1 \\ R_L = 600\Omega, V_O = 500 \text{ mV}_{PP} $	0.004	%	

(1) Typical Values represent the most likely parametric norm.

(2) Connected as voltage follower with 1V step input. Number specified is the slower of the positive and negative slew rate.

### **5V DC Electrical Characteristics**

Unless otherwise specified, all limits specified for  $T_J = 25^{\circ}C$ .  $V^+ = 5V$ ,  $V^- = 0V$ ,  $V_{CM} = V^+/2$ ,  $V_O = V^+/2$  and  $R_L > 1 M\Omega$ . Boldface limits apply at the temperature extremes.

	Parameter	Тур <sup>(1)</sup>	Limit <sup>(2)</sup>	Units	
V <sub>OS</sub>	Input Offset Voltage		-0.08	3 <b>3.5</b>	mV max
TCV <sub>OS</sub>	Input Offset Voltage Average Drift		0.6		µV/°C
I <sub>B</sub>	Input Bias Current		260		nA
I <sub>OS</sub>	Input Offset Current		25		nA
CMRR	Common Mode Rejection Ratio	$0V \le V_{CM} \le 4.1V$	89	70 <b>64</b>	dB min
PSRR	Power Supply Rejection Ratio	$2.2V \le V^+ \le 5.0V, V_0 = 0 V_{CM} = 0$	90	70 <b>64</b>	dB min
V <sub>CM</sub>	Input Common-Mode Voltage Range	For CMRR ≥ 50dB	-0.30		V
			4.1		V

(1) Typical Values represent the most likely parametric norm.

<sup>(2)</sup> All limits are specified by testing or statistical analysis.



www.ti.com

# 5V DC Electrical Characteristics (continued)

Unless otherwise specified, all limits specified for  $T_J = 25^{\circ}C$ .  $V^+ = 5V$ ,  $V^- = 0V$ ,  $V_{CM} = V^+/2$ ,  $V_O = V^+/2$  and  $R_L > 1 \text{ M}\Omega$ . **Boldface** limits apply at the temperature extremes.

Parameter		Test Conditions	Тур <sup>(1)</sup>	Limit <sup>(2)</sup>	Units
A <sub>V</sub>	Large Signal Voltage Gain	$R_L = 600\Omega$ V <sub>O</sub> = 0.75V to 4.80V	87	80 <b>70</b>	dB min
		$R_L = 2k\Omega,$ V <sub>O</sub> = 0.70V to 4.90V,	94	85 <b>70</b>	dB min
Vo	Output Swing	$R_L = 600\Omega$ to V <sup>+</sup> /2	4.882	4.840 <b>4.815</b>	V min
			0.134	0.190 <b>0.215</b>	V max
		$R_L = 2k\Omega$ to V <sup>+</sup> /2	4.952	4.930 <b>4.905</b>	V min
			0.076	0.110 <b>0.135</b>	V max
I <sub>0</sub>	Output Current	Sourcing, $V_O = 0V$ $V_{IN}(diff) = \pm 0.5V$	52.6	25.0 <b>12.0</b>	mA min
	Sinking, $V_O = 5V$ $V_{IN}$ (diff) = ±0.5V	23.7	15.0 <b>8.5</b>	mA min	
۱ <sub>s</sub>	Supply Current	LMV721-N	1.03	1.4 <b>1.7</b>	mA
		LMV722	2.01	2.4 <b>2.8</b>	max

## **5V AC Electrical Characteristics**

Unless otherwise specified, all limits specified for  $T_J = 25^{\circ}C$ .  $V^+ = 5V$ ,  $V^- = 0V$ ,  $V_{CM} = V^+/2$ ,  $V_O = V^+/2$  and  $R_{\perp} > 1 \text{ M}\Omega$ . Boldface limits apply at the temperature extremes.

Parameter		Test Conditions	Тур <sup>(1)</sup>	Units	
SR	Slew Rate	(2)	5.25	V/µs	
GBW	Gain-Bandwidth Product		10.0	MHz	
Φ <sub>m</sub>	Phase Margin		72	Deg	
G <sub>m</sub>	Gain Margin		-11	dB	
en	Input-Related Voltage Noise	f = 1 kHz	8.5	nV/√Hz	
i <sub>n</sub>	Input-Referred Current Noise	f = 1 kHz	0.2	pa/√ <del>Hz</del>	
THD	Total Harmonic Distortion	$      f = 1 kHz, A_V = 1 \\ R_L = 600\Omega, V_O = 1 V_{PP} $	0.001	%	

(1) Typical Values represent the most likely parametric norm.

(2) Connected as voltage follower with 1V step input. Number specified is the slower of the positive and negative slew rate.

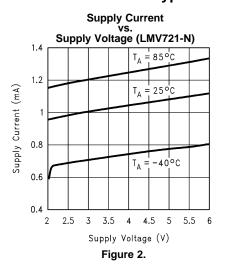
Copyright © 1999–2013, Texas Instruments Incorporated

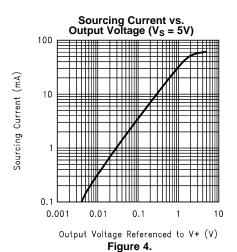


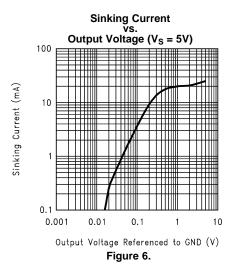
**EXAS** 

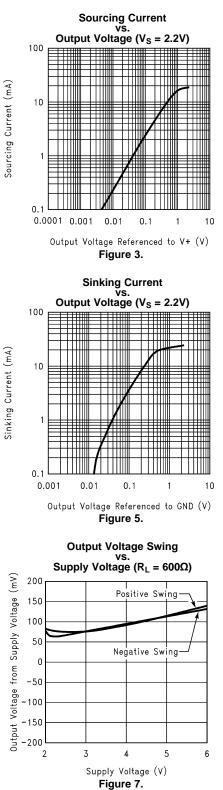
INSTRUMENTS

**Typical Performance Characteristics** 



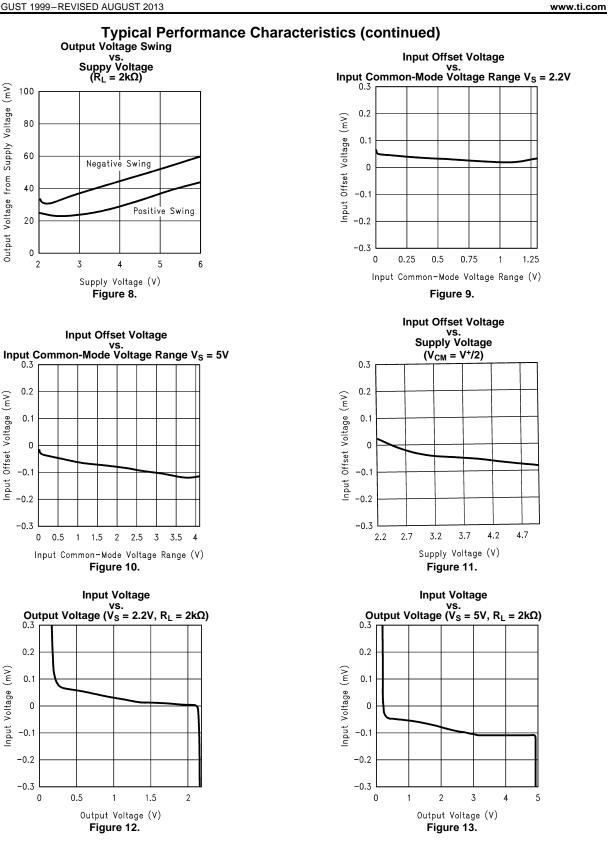






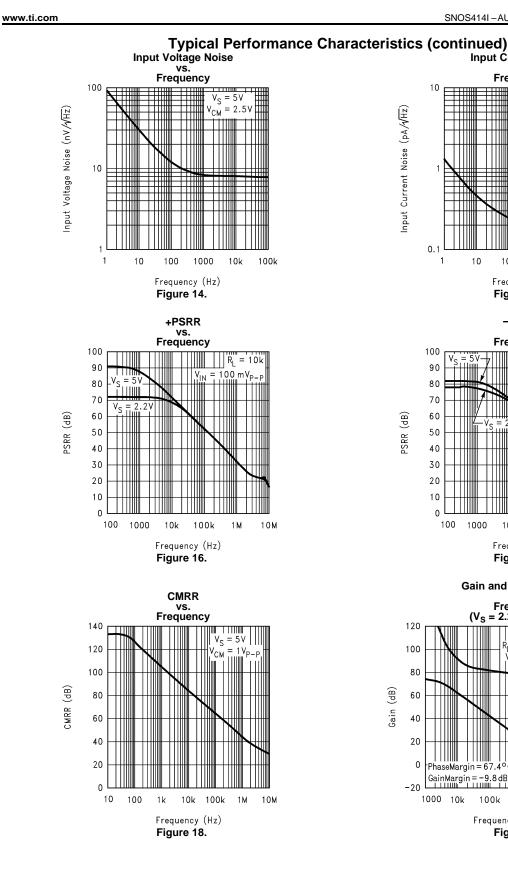
Texas **NSTRUMENTS** 

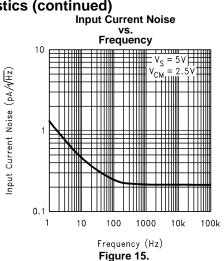
#### SNOS414I-AUGUST 1999-REVISED AUGUST 2013



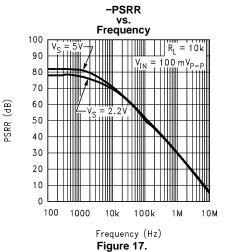
6

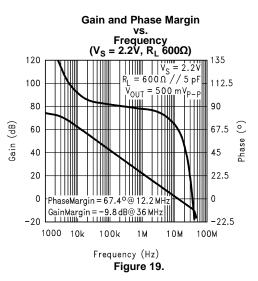












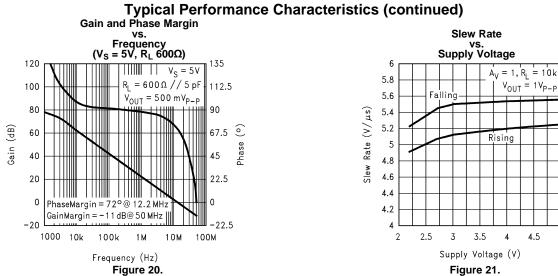
Copyright © 1999-2013, Texas Instruments Incorporated



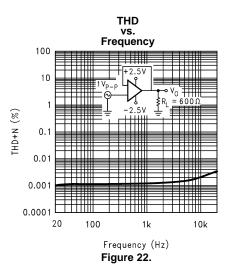
5

www.ti.com

## SNOS414I - AUGUST 1999 - REVISED AUGUST 2013









www.ti.com

#### SNOS414I - AUGUST 1999 - REVISED AUGUST 2013

## **APPLICATION NOTES**

### **BENEFITS OF THE LMV721-N/722 SIZE**

The small footprints of the LMV721-N/722 packages save space on printed circuit boards, and enable the design of smaller electronic products, such as cellular phones, pagers, or other portable systems. The low profile of the LMV721-N/722 make them possible to use in PCMCIA type III cards.

- **Signal Integrity** Signals can pick up noise between the signal source and the amplifier. By using a physically smaller amplifier package, the LMV721-N/722 can be placed closer to the signal source, reducing noise pickup and increasing signal integrity.
- **Simplified Board Layout** These products help you to avoid using long pc traces in your pc board layout. This means that no additional components, such as capacitors and resistors, are needed to filter out the unwanted signals due to the interference between the long pc traces.
- Low Supply Current These devices will help you to maximize battery life. They are ideal for battery powered systems.
- Low Supply Voltage TI provides ensured performance at 2.2V and 5V. These specifications ensure operation throughout the battery lifetime.
- **Rail-to-Rail Output** Rail-to-rail output swing provides maximum possible dynamic range at the output. This is particularly important when operating on low supply voltages.
- Input Includes Ground Allows direct sensing near GND in single supply operation.

Protection should be provided to prevent the input voltages from going negative more than -0.3V (at 25°C). An input clamp diode with a resistor to the IC input terminal can be used.

## CAPACITIVE LOAD TOLERANCE

The LMV721-N/722 can directly drive 4700pF in unity-gain without oscillation. The unity-gain follower is the most sensitive configuration to capacitive loading. Direct capacitive loading reduces the phase margin of amplifiers. The combination of the amplifier's output impedance and the capacitive load induces phase lag. This results in either an underdamped pulse response or oscillation. To drive a heavier capacitive load, circuit in Figure 23 can be used.

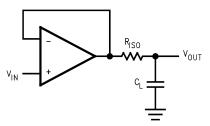


Figure 23. Indirectly Driving A capacitive Load Using Resistive Isolation

In Figure 23, the isolation resistor R<sub>ISO</sub> and the load capacitor C<sub>L</sub> form a pole to increase stability by adding more phase margin to the overall system. the desired performance depends on the value of R<sub>ISO</sub>. The bigger the R<sub>ISO</sub> resistor value, the more stable V<sub>OUT</sub> will be. Figure 24 is an output waveform of Figure 23 using 100k $\Omega$  for R<sub>ISO</sub> and 2000µF for C<sub>L</sub>.



www.ti.com

SNOS414I - AUGUST 1999 - REVISED AUGUST 2013

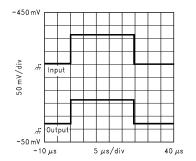


Figure 24. Pulse Response of the LMV721-N Circuit in Figure 23

The circuit in Figure 25 is an improvement to the one in Figure 23 because it provides DC accuracy as well as AC stability. If there were a load resistor in Figure 23, the output would be voltage divided by  $R_{ISO}$  and the load resistor. Instead, in Figure 25,  $R_F$  provides the DC accuracy by using feed-forward techniques to connect  $V_{IN}$  to  $R_L$ . Caution is needed in choosing the value of  $R_F$  due to the input bias current of the LMV721-N/722.  $C_F$  and  $R_{ISO}$  serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving phase margin in the overall feedback loop. Increased capacitive drive is possible by increasing the value of  $C_F$ . This in turn will slow down the pulse response.

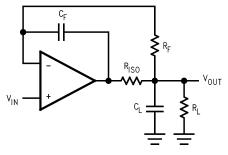
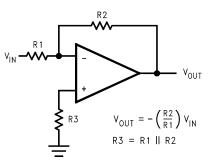


Figure 25. Indirectly Driving A Capacitive Load with DC Accuracy

### INPUT BIAS CURRENT CANCELLATION

The LMV721-N/722 family has a bipolar input stage. The typical input bias current of LMV721-N/722 is 260nA with 5V supply. Thus a  $100k\Omega$  input resistor will cause 26mV of error voltage. By balancing the resistor values at both inverting and non-inverting inputs, the error caused by the amplifier's input bias current will be reduced. The circuit in Figure 26 shows how to cancel the error caused by input bias current.







#### www.ti.com

### **TYPICAL SINGLE-SUPPLY APPLICATION CIRCUITS**

#### **Difference Amplifier**

The difference amplifier allows the subtraction of two voltages or, as a special case, the cancellation of a signal common to two inputs. It is useful as a computational amplifier, in making a differential to single-ended conversion or in rejecting a common mode signal.

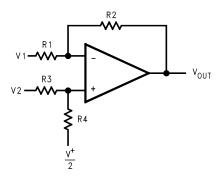


Figure 27. Difference Application

(1)

(2)	

#### **Instrumentation Circuits**

for R1 = R3 and R2 = R4 V<sub>OUT</sub> =  $\frac{R2}{R1}(V_2 - V_1) + \frac{V^+}{2}$ 

The input impendance of the previous difference amplifier is set by the resistor  $R_1$ ,  $R_2$ ,  $R_3$  and  $R_4$ . To eliminate the problems of low input impendance, one way is to use a voltage follower ahead of each input as shown in the following two instrumentation amplifiers.

#### Three-op-amp Instrumentation Amplifier

 $V_{OUT} = \left(\frac{R1 + R2}{R3 + R4}\right)\frac{R4}{R1}V_2 - \frac{R2}{R1}V_1 + \left(\frac{R1 + R2}{R3 + R4}\right)\frac{R3}{R1} \cdot \frac{V^+}{2}$ 

The LMV721-N/722 can be used to build a three-op-amp instrumentation amplifier as shown in Figure 28

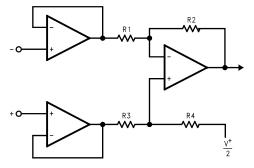


Figure 28. Three-op-amp Instrumentation Amplifier

The first stage of this instrumentation amplifier is a differential-input, differential-output amplifier, with two voltage followers. These two voltage followers assure that the input impedance is over 100M $\Omega$ . The gain of this instrumentation amplifier is set by the ratio of  $R_2/R_1$ .  $R_3$  should equal  $R_1$  and  $R_4$  equal  $R_2$ . Matching of  $R_3$  to  $R_1$  and  $R_4$  to  $R_2$  affects the CMRR. For good CMRR over temperature, low drift resistors should be used. Making  $R_4$  slightly smaller than  $R_2$  and adding a trim pot equal to twice the difference between  $R_2$  and  $R_4$  will allow the CMRR to be adjusted for optimum.

Copyright © 1999–2013, Texas Instruments Incorporated

# Two-op-amp Instrumentation Amplifier

A two-op-amp instrumentation amplifier can also be used to make a high-input impedance DC differential amplifier (Figure 29). As in the two-op-amp circuit, this instrumentation amplifier requires precise resistor matching for good CMRR.  $R_4$  should equal to  $R_1$  and  $R_3$  should equal  $R_2$ .



$$V_0 = \left(1 + \frac{R4}{R3}\right) (V_2 - V_1)$$
, where R1 = R4 and R2 = R3  
As shown:  $V_0 = 2(V_2 - V_1)$ 

## Single-Supply Inverting Amplifier

There may be cases where the input signal going into the amplifier is negative. Because the amplifier is operating in single supply voltage, a voltage divider using  $R_3$  and  $R_4$  is implemented to bias the amplifier so the input signal is within the input common-common voltage range of the amplifier. The capacitor  $C_1$  is placed between the inverting input and resistor  $R_1$  to block the DC signal going into the AC signal source,  $V_{IN}$ . The values of  $R_1$  and  $C_1$  affect the cutoff frequency, fc =  $\frac{1}{2}\pi R_1 C_1$ .

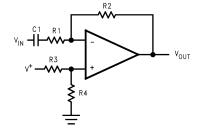
As a result, the output signal is centered around mid-supply (if the voltage divider provides  $V^+/2$  at the non-inverting input). The output can swing to both rails, maximizing the signal-to-noise ratio in a low voltage system.

### Figure 30. Single-Supply Inverting Amplifier

#### Simple Low-Pass Active Filter

 $V_{OUT} = -\frac{R2}{R1}V_{IN}$ 

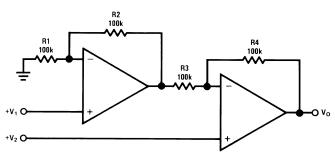
The simple low-pass filter is shown in Figure 31. Its low-pass frequency gain ( $\omega \rightarrow o$ ) is defined by  $-R_3/R_1$ . This allows low-frequency gains other than unity to be obtained. The filter has a -20dB/decade roll-off after its corner frequency fc.  $R_2$  should be chosen equal to the parallel combination of  $R_1$  and  $R_3$  to minimize error due to bias current. The frequency response of the filter is shown in Figure 32.



(3)

**ISTRUMENTS** 

FXAS



www.ti.com

FXAS

NSTRUMENTS

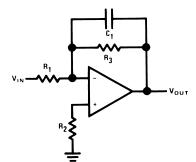


Figure 31. Simple Low-Pass Active Filter

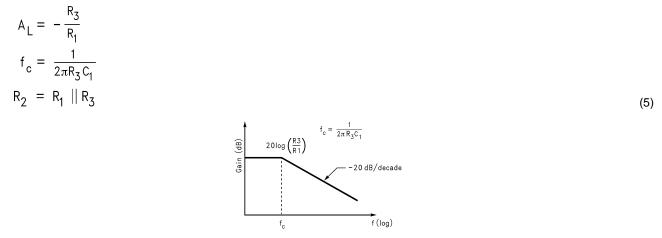


Figure 32. Frequency Response of Simple Low-pass Active Filter in Figure 31

Note that the single-op-amp active filters are used in to the applications that require low quality factor,  $Q(\le 10)$ , low frequency ( $\le 5$ KHz), and low gain ( $\le 10$ ), or a small value for the product of gain times  $Q(\le 100)$ . The op amp should have an open loop voltage gain at the highest frequency of interest at least 50 times larger than the gain of the filter at this frequency. In addition, the selected op amp should have a slew rate that meets the following requirement:

Slew Rate  $\ge 0.5 \text{ x} (\omega_{\text{H}} \text{ V}_{\text{OPP}}) \text{ X } 10^{-6} \text{V/}\mu\text{sec}$ 

#### where

- $\omega_H$  is the highest frequency of interest
- V<sub>OPP</sub> is the output peak-to-peak voltage

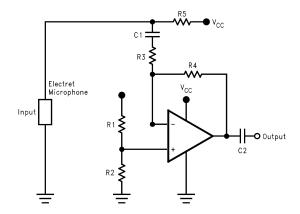


Figure 33. A Battery Powered Microphone Preamplifier

# LMV721-N, LMV722-N

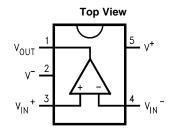


www.ti.com

#### SNOS414I - AUGUST 1999 - REVISED AUGUST 2013

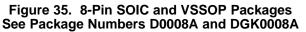
Here is a LMV721-N used as a microphone preamplifier. Since the LMV721-N is a low noise and low power op amp, it makes it an ideal candidate as a battery powered microphone preamplifier. The LMV721-N is connected in an inverting configuration. Resistors,  $R_1 = R_2 = 4.7k\Omega$ , sets the reference half way between  $V_{CC} = 3V$  and ground. Thus, this configures the op amp for single supply use. The gain of the preamplifier, which is 50 (34dB), is set by resistors  $R_3 = 10k\Omega$  and  $R_4 = 500k\Omega$ . The gain bandwidth product for the LMV721-N is 10 MHz. This is sufficient for most audio application since the audio range is typically from 20 Hz to 20kHz. A resistor  $R_5 = 5k\Omega$  is used to bias the electret microphone. Capacitors  $C_1 = C_2 = 4.7\mu$ F placed at the input and output of the op amp to block out the DC voltage offset.

#### **Connection Diagrams**



OUT A 1 8 V<sup>+</sup> - IN A 2 7 OUT B + IN A 3 6 - IN B V<sup>-</sup> 4 5 + IN B

Figure 34. 5-Pin SC70 and SOT-23 Packages See Package Numbers DCK0005A AND DBV0005A



15

Submit Documentation Feedback

SNOS414I - AUGUST 1999 - REVISED AUGUST 2013

# **REVISION HISTORY**

# **Changes from Revisio** Changed layout of National Data Sheet to TI format ...... 14

# EXAS STRUMENTS

www.ti.com



on G (March 2013) to Revision H	Page



9-Aug-2013

# **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LMV721M5	ACTIVE	SOT-23	DBV	5	1000	TBD	Call TI	Call TI	-40 to 85	A30A	Samples
LMV721M5/NOPB	ACTIVE	SOT-23	DBV	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	A30A	Samples
LMV721M5X	ACTIVE	SOT-23	DBV	5	3000	TBD	Call TI	Call TI	-40 to 85	A30A	Samples
LMV721M5X/NOPB	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	A30A	Samples
LMV721M7	ACTIVE	SC70	DCK	5	1000	TBD	Call TI	Call TI	-40 to 85	A20	Samples
LMV721M7/NOPB	ACTIVE	SC70	DCK	5	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	A20	Samples
LMV721M7X	ACTIVE	SC70	DCK	5	3000	TBD	Call TI	Call TI	-40 to 85	A20	Samples
LMV721M7X/NOPB	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	A20	Samples
LMV722M	ACTIVE	SOIC	D	8	95	TBD	Call TI	Call TI	-40 to 85	LMV 722M	Samples
LMV722M/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMV 722M	Samples
LMV722MM	ACTIVE	VSSOP	DGK	8	1000	TBD	Call TI	Call TI	-40 to 85	V722	Samples
LMV722MM/NOPB	ACTIVE	VSSOP	DGK	8	1000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	V722	Samples
LMV722MMX	ACTIVE	VSSOP	DGK	8	3500	TBD	Call TI	Call TI	-40 to 85	V722	Samples
LMV722MMX/NOPB	ACTIVE	VSSOP	DGK	8	3500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	V722	Samples
LMV722MX	ACTIVE	SOIC	D	8	2500	TBD	Call TI	Call TI	-40 to 85	LMV 722M	Samples
LMV722MX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	LMV 722M	Samples

<sup>(1)</sup> The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect. NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.



www.ti.com

9-Aug-2013

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available. **OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

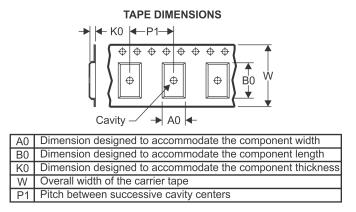
# PACKAGE MATERIALS INFORMATION

www.ti.com

Texas Instruments

## TAPE AND REEL INFORMATION





# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



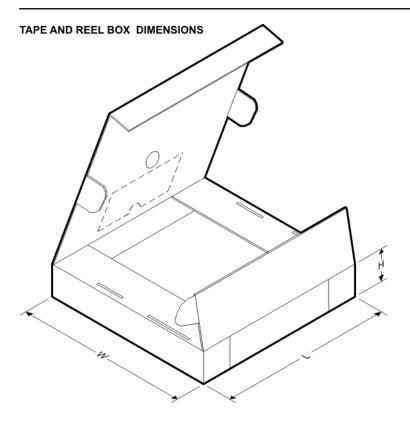
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV721M5	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV721M5/NOPB	SOT-23	DBV	5	1000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV721M5X	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV721M5X/NOPB	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
LMV721M7	SC70	DCK	5	1000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
LMV721M7/NOPB	SC70	DCK	5	1000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
LMV721M7X	SC70	DCK	5	3000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
LMV721M7X/NOPB	SC70	DCK	5	3000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
LMV722MM	VSSOP	DGK	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV722MM/NOPB	VSSOP	DGK	8	1000	178.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV722MMX	VSSOP	DGK	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV722MMX/NOPB	VSSOP	DGK	8	3500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
LMV722MX	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMV722MX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

TEXAS INSTRUMENTS

www.ti.com

# PACKAGE MATERIALS INFORMATION

12-Aug-2013



*All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV721M5	SOT-23	DBV	5	1000	210.0	185.0	35.0
LMV721M5/NOPB	SOT-23	DBV	5	1000	210.0	185.0	35.0
LMV721M5X	SOT-23	DBV	5	3000	210.0	185.0	35.0
LMV721M5X/NOPB	SOT-23	DBV	5	3000	210.0	185.0	35.0
LMV721M7	SC70	DCK	5	1000	210.0	185.0	35.0
LMV721M7/NOPB	SC70	DCK	5	1000	210.0	185.0	35.0
LMV721M7X	SC70	DCK	5	3000	210.0	185.0	35.0
LMV721M7X/NOPB	SC70	DCK	5	3000	210.0	185.0	35.0
LMV722MM	VSSOP	DGK	8	1000	210.0	185.0	35.0
LMV722MM/NOPB	VSSOP	DGK	8	1000	210.0	185.0	35.0
LMV722MMX	VSSOP	DGK	8	3500	367.0	367.0	35.0
LMV722MMX/NOPB	VSSOP	DGK	8	3500	367.0	367.0	35.0
LMV722MX	SOIC	D	8	2500	367.0	367.0	35.0
LMV722MX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0

DBV (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-178 Variation AA.



DBV (R-PDSO-G5)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.

- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
  - B. This drawing is subject to change without notice.
  - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
  - D. Falls within JEDEC MO-203 variation AA.



DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.

- D Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



#### **IMPORTANT NOTICE**

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products		Applications			
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive		
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications		
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers		
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps		
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy		
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial		
Interface	interface.ti.com	Medical	www.ti.com/medical		
Logic	logic.ti.com	Security	www.ti.com/security		
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense		
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video		
RFID	www.ti-rfid.com				
OMAP Applications Processors	www.ti.com/omap	TI E2E Community	e2e.ti.com		
Wireless Connectivity	www.ti.com/wirelessconnectivity				

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2013, Texas Instruments Incorporated